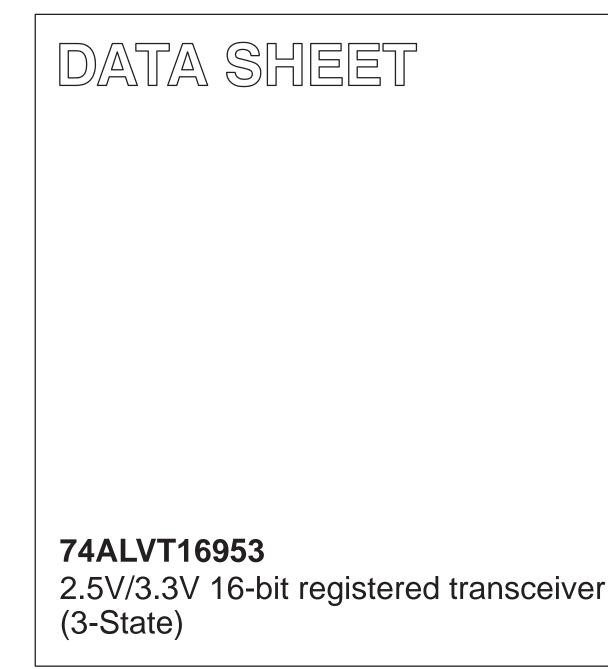
# INTEGRATED CIRCUITS



Product specification Supersedes data of 1995 Sep 19 IC23 Data Handbook

1998 Mar 26



Philips Semiconductors

### 74ALVT16953

#### **FEATURES**

- Two 8-bit registered transceivers
- 5V I/O Compatible
- 3-State buffers
- Output capability: +64mA/–32mA
- TTL input and output switching levels
- Input and output interface capability to systems at 5V supply
- Bus hold data inputs eliminate the need for external pull-up resistors to hold unused inputs
- Live insertion/extraction permitted
- Power-up 3-State
- Power-up reset
- No bus current loading when output is tied to 5V bus
- Latch-up protection exceeds 500mA per JEDEC Std 17
- ESD protection exceeds 2000V per MIL STD 883 Method 3015 and 200V per Machine Model

#### QUICK REFERENCE DATA

#### DESCRIPTION

The 74ALVT16953 is a high-performance BiCMOS product designed for  $V_{CC}$  operation at 2.5V or 3.3V with I/O compatibility up to 5V.

The 74ALVT16953 is a dual octal registered inverting transceiver. Two 8-bit registers store data flowing in both directions between two bidirectional buses. Data applied to the inputs is entered and stored on the rising edge of the Clock (nCPXX) provided that the Clock Enable (nCEXX) is Low. The data is then present at the 3-State output buffers, but is only accessible when the Output Enable (nOEXX) is Low. Data flow from A inputs to B outputs is the same as for B inputs to A outputs.

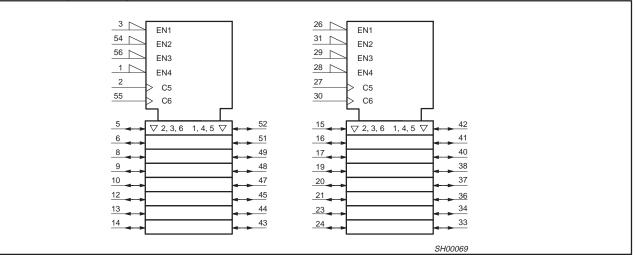
Active bus hold circuitry is provided to hold unused or floating data inputs at a valid logic level.

SYMBOL	PARAMETER	CONDITIONS	TYPI	UNIT	
STWBOL	FARAMETER	$T_{amb} = 25^{\circ}C; GND = 0V$	2.5V	3.3V	UNIT
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation delay nCPBA to nAx or nCPAB to nBx	C <sub>L</sub> = 50pF;	3.0 3.0	2.2 2.3	ns
C <sub>IN</sub>	Input capacitance	$V_{I} = 0V \text{ or } V_{CC}$	3	3	pF
C <sub>I/O</sub>	I/O pin capacitance	V <sub>I/O</sub> = 0V or V <sub>CC</sub> Outputs disabled	9	9	pF
I <sub>CCZ</sub>	Total supply current	Outputs disabled	40	70	μΑ

#### **ORDERING INFORMATION**

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
56-Pin Plastic SSOP Type III	–40°C to +85°C	74ALVT16953 DL	AV16953 DL	SOT371-1
56-Pin Plastic TSSOP Type II	–40°C to +85°C	74ALVT16953 DGG	AV16953 DGG	SOT364-1

#### LOGIC SYMBOL (IEEE/IEC)



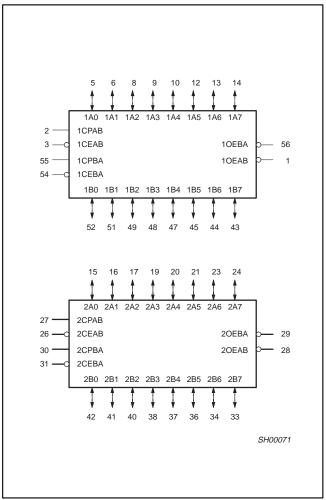
**PIN CONFIGURATION** 

# 2.5V/3.3V 16-bit registered transceiver (3-State)

## 74ALVT16953

1 OEAB		56	10EBA
1CPAB	2	55	1CPBA
1CEAB	3	54	1CEBA
GND	4	53	GND
1A0	5	52	1B0
1A1	6	51	1B1
V <sub>CC</sub>	7	50	VCC
1A2		49	1B2
1A3	9	48	1B3
1A4	10	47	1B4
GND	11	46	GND
1A5	12	45	1B5
1A6	13	44	1B6
1A7	14	43	1B7
2A0	15	42	2B0
2A1	16	41	2B1
2A2	17	40	2B2
GND	18	39	GND
2A3	19	38	2B3
2A4	20	37	2B4
2A5	21	36	2B5
Vcc	22	35	VCC
2A6	23	34	2B6
2A7	24	33	2B7
GND	25	32	GND
2CEAB	26	31	2CEBA
2CPAB	27	30	2CPBA
20EAB	28	29	20EBA
	Sł	-100070	

#### LOGIC SYMBOL



#### **PIN DESCRIPTION**

PIN NUMBER	SYMBOL	NAME AND FUNCTION
2, 55 27, 30	1CPAB / 1CPBA 2CPAB / 2CPBA	Clock input A to B / Clock input B to A
3, 54, 26, 31	1CEAB / 1CEBA 2CEAB / 2CEBA	Clock enable input A to B / Clock enable input B to A
5, 6, 8, 9, 10, 12, 13, 14, 15, 16, 17, 19, 20, 21, 23, 24	1A0 – 1A7 2A0 – 2A7	Data inputs/outputs (A side)
52, 51, 49, 48, 47, 45, 44, 43 42, 41, 40, 38, 37, 36, 34, 33	1B0 – 1B7 2B0 – 2B7	Data inputs/outputs (B side)
1, 56 28, 29	10EAB / 10EBA 20EAB / 20EBA	Output enable inputs
4, 11, 18, 25, 32, 39, 46, 53	GND	Ground (0V)
7, 22, 35, 50	V <sub>CC</sub>	Positive supply voltage

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### FUNCTION TABLE for Register nAx or nBx

11	INPUTS INTERNAL		OPERATING	
nAx or nBx	nCPXX	nCEXX	Q	MODE
Х	Х	Н	NC	Hold data
L H	$\stackrel{\wedge}{\uparrow}$	L	H L	Load data

H = High voltage level

L = Low voltage level

 $\uparrow$  = Low-to-High transition

X = Don't care

XX = AB or BA

NC=No change

### LOGIC DIAGRAM

#### **FUNCTION TABLE for Output Enable**

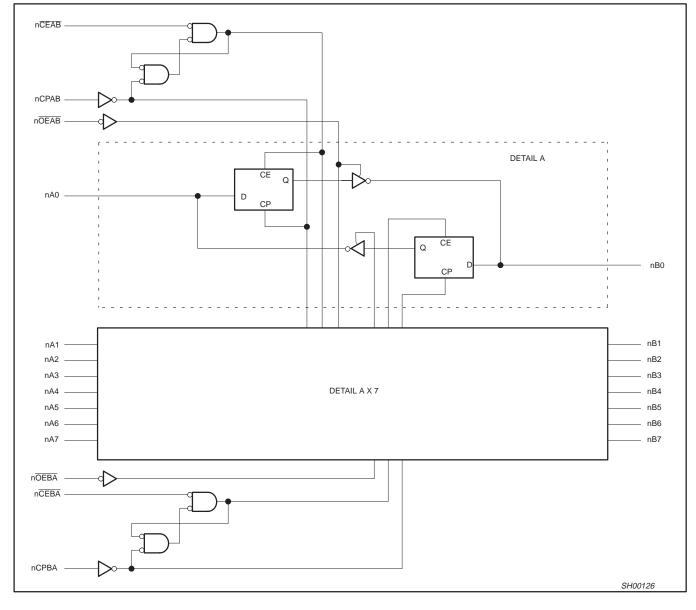
INPUTS	INTERNAL	nAx or nBx	OPERATING		
nOEXX	Q	OUTPUTS	MODE		
Н	Х	Z	Disable outputs		
L	L H	H L	Enable outputs		

H = High voltage level

L = Low voltage level

X = Don't care

XX = AB or BA Z = High impedance "off" state



### 74ALVT16953

#### ABSOLUTE MAXIMUM RATINGS<sup>1, 2</sup>

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V <sub>CC</sub>	DC supply voltage		-0.5 to +4.6	V
I <sub>IK</sub>	DC input diode current	V <sub>1</sub> < 0	-50	mA
VI	DC input voltage <sup>3</sup>		-0.5 to +7.0	V
I <sub>ОК</sub>	DC output diode current	V <sub>O</sub> < 0	-50	mA
V <sub>OUT</sub>	DC output voltage <sup>3</sup>	output in Off or High state	-0.5 to +7.0	V
I <sub>OUT</sub>	DC output current	output in Low state output in High state	128 64	mA
T <sub>stg</sub>	Storage temperature range		-65 to +150	°C

NOTES:

1. Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability. The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction

2. temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150°C. 3. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

#### **RECOMMENDED OPERATING CONDITIONS**

SYMBOL	PARAMETER		2.5V RANGE LIMITS		3.3V RANGE LIMITS	
OTHEOL		MIN	MAX	MIN	MAX	UNIT
V <sub>CC</sub>	DC supply voltage	2.3	2.7	3.0	3.6	V
VI	Input voltage	0	5.5	0	5.5	V
V <sub>IH</sub>	High-level input voltage	1.7		2.0		V
V <sub>IL</sub>	Input voltage		0.7		0.8	V
I <sub>OH</sub>	High-level output current		-8		-32	mA
le:	Low-level output current		8		32	mA
IOL	Low-level output current; current duty cycle $\leq$ 50%; f $\geq$ 1kHz		24		64	ША
Δt/Δv	Input transition rise or fall rate; Outputs enabled		10		10	ns/V
T <sub>amb</sub>	Operating free-air temperature range	-40	+85	-40	+85	°C

### 74ALVT16953

#### DC ELECTRICAL CHARACTERISTICS (3.3V $\pm$ 0.3V RANGE)

					LIMITS		
SYMBOL	PARAMETER	TEST CONDITIONS		Temp = -40°C to +85°			
				MIN	TYP <sup>1</sup>	MAX	1
V <sub>IK</sub>	Input clamp voltage	V <sub>CC</sub> = 3.0V; I <sub>IK</sub> = -18mA			-0.85	-1.2	V
V	High-level output voltage	$V_{CC} = 3.0 \text{ to } 3.6 \text{V}; I_{OH} = -100 \mu \text{A}$		V <sub>CC</sub> -0.2	V <sub>CC</sub>		v
V <sub>OH</sub>	nigh-level output voltage	V <sub>CC</sub> = 3.0V; I <sub>OH</sub> = -32mA		2.0	2.3		ĺ
		V <sub>CC</sub> = 3.0V; I <sub>OL</sub> = 100µA			0.07	0.2	
Vol	Low-level output voltage	V <sub>CC</sub> = 3.0V; I <sub>OL</sub> = 16mA			0.25	0.4	
VOL		V <sub>CC</sub> = 3.0V; I <sub>OL</sub> = 32mA			0.3	0.5	ľ
		V <sub>CC</sub> = 3.0V; I <sub>OL</sub> = 64mA			0.4	0.55	1
		$V_{CC}$ = 3.6V; $V_{I}$ = $V_{CC}$ or GND	Control pins		0.1	±1	μΑ
		V <sub>CC</sub> = 0 or 3.6V; V <sub>1</sub> = 5.5V			0.1	10	
I <sub>I</sub>	Input leakage current	$V_{CC} = 3.6V; V_1 = 5.5V$	Data pins <sup>4</sup>		0.1	10	
		$V_{CC} = 3.6V; V_{I} = V_{CC}$			0.1	1	
		$V_{CC} = 3.6V; V_I = 0$	1		0.1	-5	
I <sub>OFF</sub>	Off current	$V_{CC} = 0V; V_{I} \text{ or } V_{O} = 0 \text{ to } 4.5V$			0.1	±100	μA
	Bus Hold current	$V_{CC} = 3V; V_I = 0.8V$		75	120		μA
HOLD	A or B inputs	V <sub>CC</sub> = 3V; V <sub>I</sub> = 2.0V		-75	-130		μA
$I_{EX}$	Current into an output in the High state when $V_O > V_{CC}$	$V_{O} = 5.5V; V_{CC} = 3.0V$			50	125	μA
I <sub>PU/PD</sub>	Power up/down 3-State output current <sup>3</sup>	$V_{CC} \leq$ 1.2V; $V_{O}$ = 0.5V to $V_{CC};$ $V_{I}$ = GNE OE/OE = Don't care	) or V <sub>CC</sub> ;		40	±100	μA
I <sub>CCH</sub>		$V_{CC}$ = 3.6V; Outputs High, $V_{I}$ = GND or	V <sub>CC</sub> , I <sub>O =</sub> 0		0.07	0.1	
I <sub>CCL</sub>	Quiescent supply current	$V_{CC}$ = 3.6V; Outputs Low, $V_{I}$ = GND or $V_{CC}$	/ <sub>CC,</sub> I <sub>O =</sub> 0		3.5	5	mA
I <sub>CCZ</sub>		$V_{CC}$ = 3.6V; Outputs Disabled; $V_{I}$ = GNE	) or $V_{CC, I_{O}} = 0^5$		0.07	0.1	
$\Delta I_{CC}$	Additional supply current per input pin <sup>2</sup>	$V_{CC}$ = 3V to 3.6V; One input at V <sub>CC</sub> -0.6 Other inputs at V <sub>CC</sub> or GND	V,		0.04	0.4	mA
						-	

NOTES:

All typical values are at V<sub>CC</sub> = 3.3V and T<sub>amb</sub> = 25°C.
 This is the increase in supply current for each input at the specified voltage level other than V<sub>CC</sub> or GND
 This parameter is valid for any V<sub>CC</sub> between 0V and 1.2V with a transition time of up to 10msec. From V<sub>CC</sub> = 1.2V to V<sub>CC</sub> = 3.3V ± 0.3V a transition time of 100µsec is permitted. This parameter is valid for T<sub>amb</sub> = 25°C only.
 Unused pins at V<sub>CC</sub> or GND.

5.  $I_{CCZ}$  is measured with outputs pulled up to  $V_{CC}$  or pulled down to ground.

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#### AC CHARACTERISTICS (3.3V $\pm$ 0.3V RANGE)

GND = 0V; t<sub>R</sub> = t<sub>F</sub> = 2.5ns; C<sub>L</sub> = 50pF, R<sub>L</sub> = 500Ω; T<sub>amb</sub> =  $-40^{\circ}$ C to +85°C

SYMBOL	PARAMETER	WAVEFORM	$V_{CC}$ = 3.3V ±0.3V		UNIT	
			MIN	TYP <sup>1</sup>	МАХ	1
f <sub>MAX</sub>	Maximum clock frequency	1	125	162		MHz
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation delay nCPBA to nAx, nCPAB to nBx	1	1.0 1.0	2.2 2.3	3.4 3.3	ns
t <sub>PZH</sub> t <sub>PZL</sub>	Output enable time nOEBA to nAx, nOEAB to nBx	3 4	1.0 0.5	2.4 2.0	3.8 3.3	ns
t <sub>PHZ</sub> t <sub>PLZ</sub>	Output disable time nOEBA to nAx, nOEAB to nBx	3 4	1.0 1.0	3.2 2.3	4.6 3.6	ns

NOTES:

1. All typical values are at V\_{CC} = 3.3V and T\_{amb} = 25°C

#### AC SETUP REQUIREMENTS (3.3V ±0.3V RANGE)

GND = 0V;  $t_R = t_F = 2.5$ ns;  $C_L = 50$ pF,  $R_L = 500\Omega$ ;  $T_{amb} = -40$ °C to +85°C

			LIM		
SYMBOL	PARAMETER	WAVEFORM	V <sub>CC</sub> = 3.3	UNIT	
			MIN	TYP	
t <sub>S</sub> (H) t <sub>s</sub> (L)	Setup time nAx to nCPAB or nBx to nCPBA	2	1.5 1.5	0.9 0.5	ns
t <sub>h</sub> (H) t <sub>h</sub> (L)	Hold time nAx to nCPAB or nBx to nCPBA	2	0.5 0.5	-0.5 -0.9	ns
t <sub>s</sub> (H) t <sub>s</sub> (L)	Setup time nCEAB to nCPAB, nCEBA to nCPBA	2	1.1 0.5	0.2 0.5	ns
t <sub>h</sub> (H) t <sub>h</sub> (L)	Hold time nCEAB to nCPAB, nCEBA to nCPBA	2	1.5 1.0	0.6 0.1	ns
t <sub>w</sub> (H) t <sub>w</sub> (L)	nCPAB or nCPBA pulse width, High or Low	1	3.2 2.2	2.6 1.5	ns

### 74ALVT16953

#### DC ELECTRICAL CHARACTERISTICS (2.5V $\pm$ 0.2V RANGE)

			LIMITS				
SYMBOL	PARAMETER	TEST CONDITIONS	TEST CONDITIONS		-40°C to	+85°C	
				MIN	TYP <sup>1</sup>	MAX	1
VIK	Input clamp voltage	V <sub>CC</sub> = 2.3V; I <sub>IK</sub> = -18mA			-0.85	-1.2	V
M	High-level output voltage	$V_{CC} = 2.3$ to 3.6V; $I_{OH} = -100\mu A$		V <sub>CC</sub> -0.2	V <sub>CC</sub>		v
V <sub>OH</sub>	High-level output voltage	V <sub>CC</sub> = 2.3V; I <sub>OH</sub> = -8mA		1.8	2.1		1 `
		V <sub>CC</sub> = 2.3V; I <sub>OL</sub> = 100µA			0.07	0.2	
V <sub>OL</sub>	Low-level output voltage	V <sub>CC</sub> = 2.3V; I <sub>OL</sub> = 24mA			0.3	0.5	V
		V <sub>CC</sub> = 2.3V; I <sub>OL</sub> = 8mA			0.3	0.4	1
		$V_{CC}$ = 2.7V; $V_{I}$ = $V_{CC}$ or GND	Control pins		0.1	±1	
		$V_{CC} = 0 \text{ or } 2.7 \text{V}; \text{ V}_{I} = 5.5 \text{V}$	Data pins <sup>4</sup>		0.1	10	1
I <sub>I</sub>	Input leakage current	V <sub>CC</sub> = 2.7V; V <sub>1</sub> = 5.5V			0.1	10	μA
		$V_{CC} = 2.7V; V_{I} = V_{CC}$			0.1	1	
		$V_{CC} = 2.7V; V_1 = 0$	1		0.1	-5	1
I <sub>OFF</sub>	Off current	$V_{CC} = 0V$ ; $V_{I}$ or $V_{O} = 0$ to 4.5V			0.1	±100	μΑ
luce -	Bus Hold current	V <sub>CC</sub> = 2.5V; V <sub>1</sub> = 0.7V			110		μΑ
HOLD	A or B inputs <sup>6</sup>	V <sub>CC</sub> = 2.5V; V <sub>I</sub> = 1.7V			-6		μΑ
$I_{EX}$	Current into an output in the High state when $V_O > V_{CC}$	$V_{O} = 5.5V; V_{CC} = 2.3V$			50	125	μA
I <sub>PU/PD</sub>	Power up/down 3-State output current <sup>3</sup>	$V_{CC}$ $\leq$ 1.2V; $V_{O}$ = 0.5V to $V_{CC};$ $V_{I}$ = GNE OE/OE = Don't care	) or V <sub>CC</sub> ;		40	100	μA
I <sub>CCH</sub>		$V_{CC}$ = 2.7V; Outputs High, $V_I$ = GND or $V_{CC}$ , $I_O$ = 0 $V_{CC}$ = 2.7V; Outputs Low, $V_I$ = GND or $V_{CC}$ , $I_O$ = 0			0.04	0.1	
I <sub>CCL</sub>	Quiescent supply current				2.5	4.5	mA
I <sub>CCZ</sub>		$V_{CC}$ = 2.7V; Outputs Disabled; $V_{I}$ = GND	) or $V_{CC}$ , $I_{O} = 0^5$		0.04	0.1	
$\Delta I_{CC}$	Additional supply current per input pin <sup>2</sup>	$V_{CC}$ = 2.3V to 2.7V; One input at $V_{CC}$ -0. Other inputs at $V_{CC}$ or GND	.6V,		0.01	0.4	mA

NOTES:

 All typical values are at V<sub>CC</sub> = 2.5V and T<sub>amb</sub> = 25°C.
 This is the increase in supply current for each input at the specified voltage level other than V<sub>CC</sub> or GND
 This parameter is valid for any V<sub>CC</sub> between 0V and 1.2V with a transition time of up to 10msec. From V<sub>CC</sub> = 1.2V to V<sub>CC</sub> = 2.5V ± 0.3V a transition time of 100µsec is permitted. This parameter is valid for T<sub>amb</sub> = 25°C only.
 Unused pins at V<sub>CC</sub> or GND.
 I<sub>CCZ</sub> is measured with outputs pulled up to V<sub>CC</sub> or pulled down to ground.
 Bus bold current is not specified below V<sub>CC</sub> = 2.5V ± 0.3V a transition time of the poly V<sub>CC</sub> or pulled down to ground.

6. Bus hold current is not specified below  $V_{CC}$  =

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#### AC CHARACTERISTICS (2.5V $\pm$ 0.2V RANGE)

GND = 0V;  $t_R = t_F = 2.5ns$ ;  $C_L = 50pF$ ,  $R_L = 500\Omega$ ;  $T_{amb} = -40^{\circ}C$  to +85°C

		WAVEFORM		UNIT		
SYMBOL	PARAMETER		V <sub>CC</sub> = 2.5V ±0.2V			
			MIN	TYP <sup>1</sup>	MAX	1
f <sub>MAX</sub>	Maximum clock frequency	1	100	131		MHz
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation delay nCPBA to nAx, nCPAB to nBx	1	1.0 1.0	3.0 3.0	4.6 4.7	ns
t <sub>PZH</sub> t <sub>PZL</sub>	Output enable time nOEBA to nAx, nOEAB to nBx	3 4	1.0 1.0	3.6 2.7	6.0 4.5	ns
t <sub>PHZ</sub> t <sub>PLZ</sub>	Output disable time nOEBA to nAx, nOEAB to nBx	3 4	1.0 1.0	3.9 3.2	6.7 5.4	ns

NOTES:

1. All typical values are at V<sub>CC</sub> = 2.5V and  $T_{amb}$  = 25°C

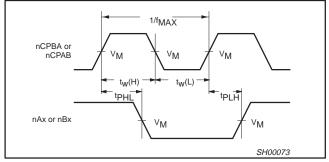
#### AC SETUP REQUIREMENTS (2.5V ±0.2V RANGE)

GND = 0V;  $t_R = t_F = 2.5ns$ ;  $C_L = 50pF$ ,  $R_L = 500\Omega$ ;  $T_{amb} = -40^{\circ}C$  to  $+85^{\circ}C$ 

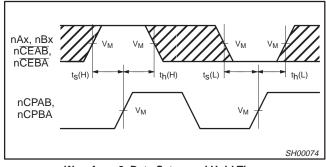
			LIM	ITS	
SYMBOL	PARAMETER	WAVEFORM	V <sub>CC</sub> = 2.5	5V ±0.2V	UNIT
			MIN	TYP	
t <sub>S</sub> (H) t <sub>s</sub> (L)	Setup time nAx to nCPAB or nBx to nCPBA	2	2.0 2.0	1.2 1.0	ns
t <sub>h</sub> (H) t <sub>h</sub> (L)	Hold time nAx to nCPAB or nBx to nCPBA	2	0.5 0.5	-0.9 -1.2	ns
t <sub>s</sub> (H) t <sub>s</sub> (L)	Setup time nCEAB to nCPAB, nCEBA to nCPBA	2	1.1 1.0	0.2 0.2	ns
t <sub>h</sub> (H) t <sub>h</sub> (L)	Hold time nCEAB to nCPAB, nCEBA to nCPBA	2	1.1 1.1	0.2 0.1	ns
t <sub>w</sub> (H) t <sub>w</sub> (L)	nCPAB or nCPBA pulse width, High or Low	1	3.2 3.0	2.7 2.4	ns

#### AC WAVEFORMS

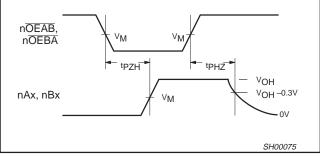
 $V_{M} = 1.5V$ ,  $V_{IN} = GND$  to 3.0V



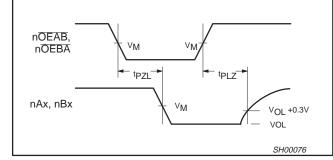
Waveform 1. Propagation Delay, Clock Input to Output, Clock Pulse Width, and Maximum Clock Frequency



Waveform 2. Data Setup and Hold Times

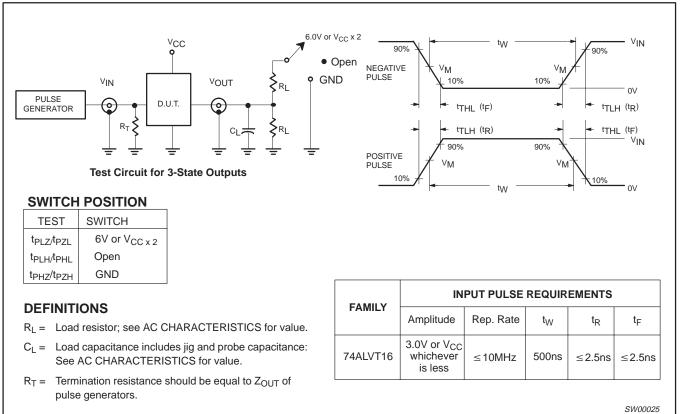






Waveform 4. 3-State Output Enable Time to Low Level and Output Disable Time from Low Level

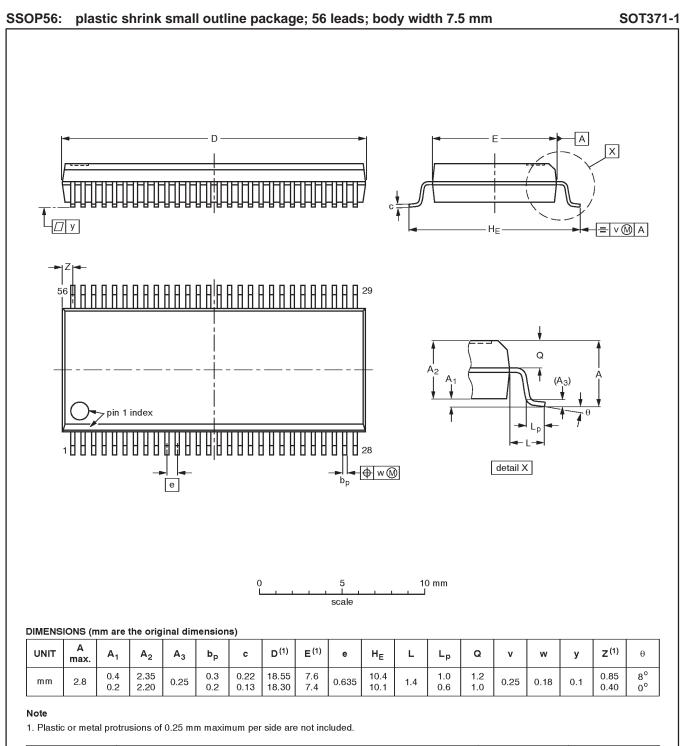
#### **TEST CIRCUIT AND WAVEFORMS**



### 74ALVT16953

### Product specification

### 74ALVT16953

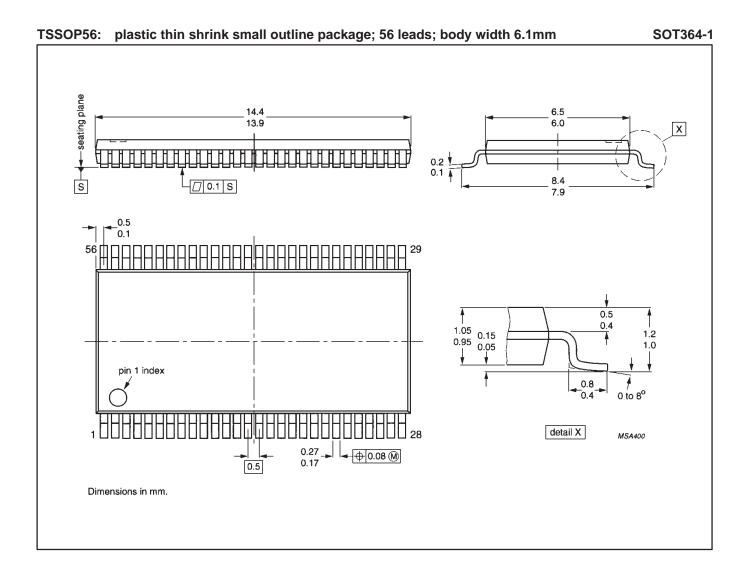


OUTLINE	REFERENCES			EUROPEAN			
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE	
SOT371-1		MO-118AB				<del>-93-11-02</del> 95-02-04	

#### Philips Semiconductors

# 2.5V/3.3V 16-bit registered transceiver (3-State)

### 74ALVT16953



# 74ALVT16953

NOTES

#### Data sheet status

Data sheet status	Product status	Definition [1]
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
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